



30V N-CHANNEL ENHANCEMENT MODE MOSFET POWERDI®

Product Summary

| V _{(BR)DSS} | R _{DS(ON)} max | I _D max T _A = 25°C |
|----------------------|-------------------------------|---|
| | $23m\Omega$ @ $V_{GS} = 10V$ | 7.5A |
| 30V | $33m\Omega$ @ $V_{GS} = 4.5V$ | 6.3 A |

Features and Benefits

- 100% Unclamped Inductive Switch (UIS) test in production
- Low R_{DS(ON)} ensures on state losses are minimized
- Small form factor thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

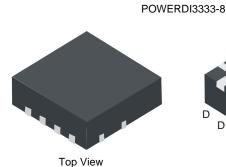
Description and Applications

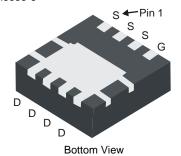
This MOSFET has been designed to minimize the on-state resistance $(R_{DS(on)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

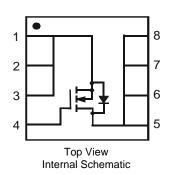
- Backlighting
- Power Management Functions
- DC-DC Converters

Mechanical Data

- Case: POWERDI3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See diagram
 Terminals: Finish Matte Tin annealed over Copper leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (approximate)







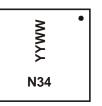
Ordering Information (Note 4)

| Dout Number | Conn | Packaging |
|---------------|---------------|------------------|
| Part Number | Case | Packaging |
| DMN3024SFG-7 | POWERDI3333-8 | 2000/Tape & Reel |
| DMN3024SFG-13 | POWERDI3333-8 | 3000/Tape & Reel |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com.

Marking Information



N34 = Product Type Marking Code YYWW = Date Code Marking YY = Last digit of year (ex: 11 = 2011) WW = Week code (01 ~ 53)



Maximum Ratings @T_A = 25°C unless otherwise specified

| Characteristic | Symbol | Value | Units | | |
|--|------------------|--|----------------|-------------|---|
| Drain-Source Voltage | V _{DSS} | 30 | V | | |
| Gate-Source Voltage | V _{GSS} | ±25 | V | | |
| Continuous Durin Courset (Note CVV 40V | Steady State | T _A = 25°C T _A = 70°C | I _D | 7.5 6.0 | А |
| Continuous Drain Current (Note 6) V _{GS} = 10V | t<10s | T _A = 25°C T _A = 70°C | ID | 10.5 8.5 | А |
| Continuous Dusis Courset (Note CVV | Steady State | T _A = 25°C T _A = 70°C | I _D | 6.3 5.0 | А |
| Continuous Drain Current (Note 6) V _{GS} = 4.5V | t<10s | T _A = 25°C T _A = 70°C | I _D | 8.5 7.6 | А |
| Pulsed Drain Current (10µs pulse, duty cycle = 1%) | I _{DM} | 60 | Α | | |
| Avalanche Current (Note 7) | I _{AS} | 9 | Α | | |
| Repetitive Avalanche Energy (Note 7) | Eas | 12 | mJ | | |

Thermal Characteristics @TA = 25°C unless otherwise specified

| Characteristic | Symbol | Value | Units | |
|--|-----------------------|-----------------|-------|------|
| Total Power Dissipation (Note 5) | T _A = 25°C | C | 0.9 | W |
| Total Power Dissipation (Note 5) | $T_A = 70$ °C | P_{D} | 0.5 | |
| Thormal Posistance, Junction to Ambient (Note 5) | Steady state | C | 145 | °C/W |
| Thermal Resistance, Junction to Ambient (Note 5) | t<10s | $R_{	heta JA}$ | 74 | |
| Total Barras Discipation (Note C) | | | 2.2 | W |
| Total Power Dissipation (Note 6) | $T_A = 70$ °C | P _D | 1.4 | VV |
| Thermal Pagistanes, Junation to Ambient (Note 6) | Steady state | | 58 | |
| Thermal Resistance, Junction to Ambient (Note 6) | | $R_{\theta JA}$ | 31 | °C/W |
| Thermal Resistance, Junction to Case (Note 6) | $R_{	heta JC}$ | 11 | | |
| Operating and Storage Temperature Range | $T_{J,}T_{STG}$ | -55 to +150 | °C | |

Notes:

^{5.} Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

^{7 .}UIS in production with L = 0.3mH, TJ = 25°C

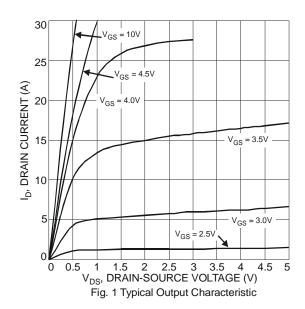


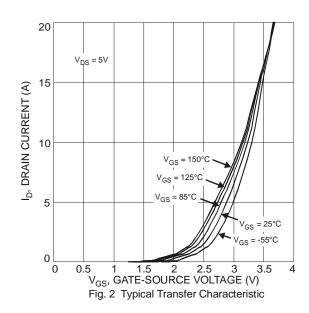
Electrical Characteristics T_A = 25°C unless otherwise specified

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|----------------------|-----|------|------|------|---|--|
| OFF CHARACTERISTICS (Note 8) | | | | | | • | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 30 | - | - | V | $V_{GS} = 0V, I_D = 250 \mu A$ | |
| Zero Gate Voltage Drain Current | I _{DSS} | - | - | 1 | μA | $V_{DS} = 30V, V_{GS} = 0V$ | |
| Gate-Source Leakage | I _{GSS} | - | - | ±100 | nA | $V_{GS} = \pm 25V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 8) | | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | 1.0 | 1.3 | 2.4 | V | $V_{DS} = V_{GS}, I_D = 250 \mu A$ | |
| Static Drain-Source On-Resistance | | - | 15 | 23 | mΩ | $V_{GS} = 10V, I_D = 10A$ | |
| Static Drain-Source On-Resistance | R _{DS (ON)} | - | 24 | 33 | | $V_{GS} = 4.5V, I_D = 7.5A$ | |
| Forward Transfer Admittance | Y _{fs} | - | 11 | - | S | $V_{DS} = 5V, I_{D} = 10.0A$ | |
| Diode Forward Voltage | V_{SD} | - | 0.69 | 1 | V | $V_{GS} = 0V, I_{S} = 1A$ | |
| DYNAMIC CHARACTERISTICS (Note 9) | | | | | | | |
| Input Capacitance | C _{iss} | - | 479 | - | pF | 151/1/ 01/ | |
| Output Capacitance | Coss | - | 97 | - | pF | $V_{DS} = 15V, V_{GS} = 0V,$ f = 1.0MHz | |
| Reverse Transfer Capacitance | C _{rss} | - | 61 | - | pF | 1 = 1.000112 | |
| Gate Resistance | R_{g} | 0.4 | 1.1 | 1.6 | Ω | $V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$ | |
| Total Gate Charge V _{GS} = 4.5V | Qg | - | 5.0 | - | nC | | |
| Total Gate Charge V _{GS} = 10V | Qg | - | 10.5 | - | nC | 1,, ,,,,,,,,, | |
| Gate-Source Charge | Q _{qs} | - | 1.8 | - | nC | V _{DS} = 15V, I _D = 10A | |
| Gate-Drain Charge | Q _{qd} | - | 1.6 | - | nC | | |
| Turn-On Delay Time | t _{D(on)} | - | 2.9 | - | ns | | |
| Turn-On Rise Time | t _r | - | 7.9 | - | ns | V _{GS} = 10V, V _{DS} = 15V, | |
| Turn-Off Delay Time | t _{D(off)} | - | 14.6 | - | ns | $R_G = 3\Omega$, $R_L = 1.5\Omega$, | |
| Turn-Off Fall Time | t _f | - | 3.1 | - | ns | | |

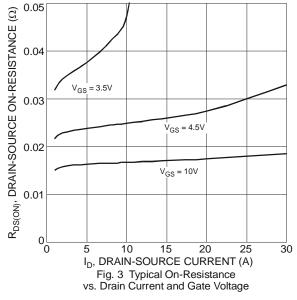
Notes:

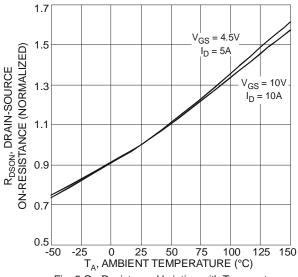
- 8. Short duration pulse test used to minimize self-heating effect.
- 9. Guaranteed by design. Not subject to product testing.

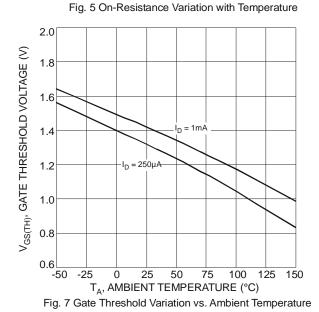


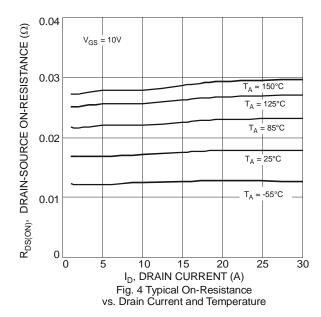


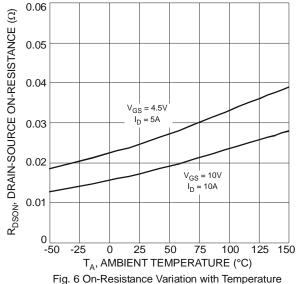




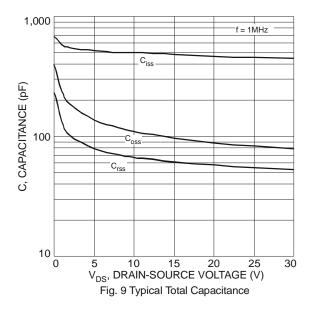


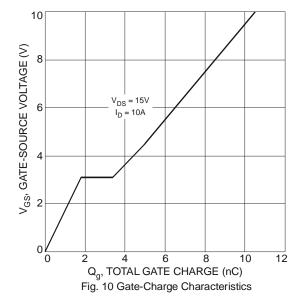


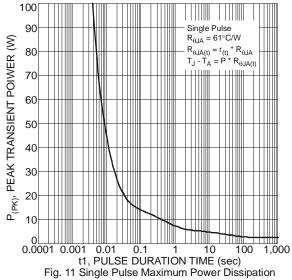


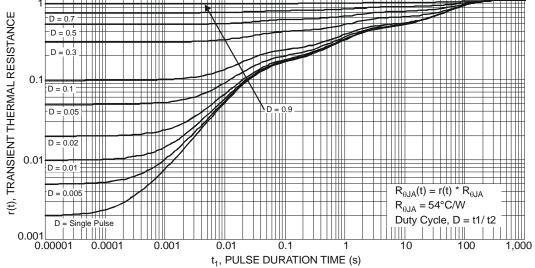






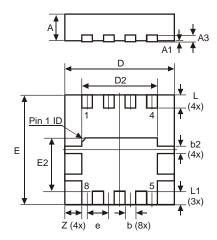






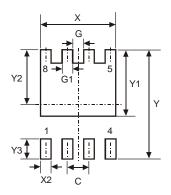


Package Outline Dimensions



| POWERDI3333-8 | | | | | |
|----------------------|------|------|-------|--|--|
| Dim | Min | Max | Тур | | |
| D | 3.25 | 3.35 | 3.30 | | |
| E | 3.25 | 3.35 | 3.30 | | |
| D2 | 2.22 | 2.32 | 2.27 | | |
| E2 | 1.56 | 1.66 | 1.61 | | |
| Α | 0.75 | 0.85 | 0.80 | | |
| A1 | 0 | 0.05 | 0.02 | | |
| A3 | _ | _ | 0.203 | | |
| b | 0.27 | 0.37 | 0.32 | | |
| b2 | _ | _ | 0.20 | | |
| L | 0.35 | 0.45 | 0.40 | | |
| L1 | _ | _ | 0.39 | | |
| е | - | - | 0.65 | | |
| Ζ | _ | _ | 0.515 | | |
| All Dimensions in mm | | | | | |

Suggested Pad Layout



| Dimensions | Value (in mm) | | | | |
|------------|---------------|--|--|--|--|
| С | 0.650 | | | | |
| G | 0.230 | | | | |
| G1 | 0.420 | | | | |
| Υ | 3.700 | | | | |
| Y1 | 2.250 | | | | |
| Y2 | 1.850 | | | | |
| Y3 | 0.700 | | | | |
| Х | 2.370 | | | | |
| X2 | 0.420 | | | | |



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